

TECHNICAL DATA DATA SHEET 6027, REV. -

HERMETIC SCHOTTKY RECTIFIER Very Low Forward Voltage Drop

Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	45	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form (Single)	60	Α
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form (Common Cathode)	120	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine wave (per leg)	860	Α
Non-Repetitive Avalanche Energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, \ I_{AS} = 3.0 \text{A}, \ L = 4.4 \text{mH (per leg)}$	20	mJ
Repetitive Avalanche Current	I _{AR}	I_{AS} decay linearly to 0 in 1 μs f limited by T_J max V_A =1.5 V_R	3.0	А
Maximum Thermal Resistance	$R_{ heta JC}$	DC operation	0.7	°C/W
Max. Junction Temperature	T_J	-	-65 to +175	°C
Max. Storage Temperature	T_{stg}	-	-65 to +175	°C

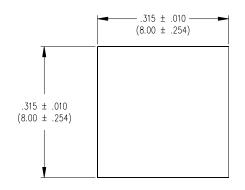
Electrical Characteristics

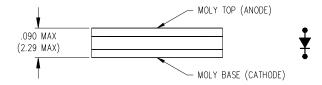
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 60A, Pulse, T _J = 25 °C	0.66	V
(per leg)	V_{F2}	@ 60A, Pulse, T _J = 125 °C	0.59	V
Max. Reverse Current	I _{R1}	@V _R = 45V, Pulse,	1.2	mA
		T _J = 25 °C		
(per leg)	I _{R2}	@V _R = 45V, Pulse,	45	mA
		T _J = 125 °C		
Max. Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 ^{\circ}C$	2400	pF
(per leg)		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

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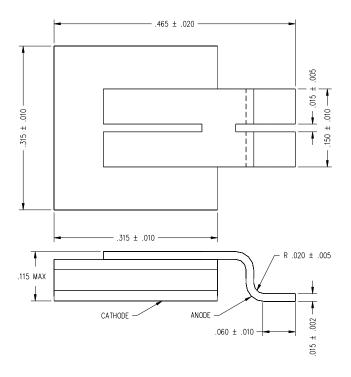
MECHANICAL DIMENSIONS: In Inches / mm

SHD-2 HIGH PROFILE





SHD-2B HIGH PROFILE



TYPE	PIN 1 (Base)	PIN 2
SINGLE RECTIFIER	CATHODE	ANODE
in a Surface Mount Package		

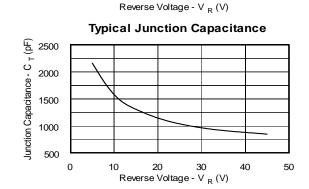
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Note: The V_f curves shown are for the unpackaged die only.

Typical Forward Characteristics 10² 175 °C 125 °C 125 °C 0.2 0.3 0.4 0.5 0.6 0.7 0.8 Forward Voltage Drop - V F (V)

Typical Reverse Characteristics 10³ 175 °C 10² Instantaneous Reverse Current - I $_{\rm R}$ (mA) 150 °C 10¹ 125 °C 100 °C 10⁰ 75 °C 10⁻¹ 50 °C 10⁻² 25 °C 10⁻³



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